CONCLUSION

As all of the outstanding rejections have been traversed and all of the claims are believed to be in condition for allowance, the Applicants respectfully request issuance of a Notice of Allowability. If the undersigned attorney can assist in any matters regarding examination of this application, the Examiner is encouraged to call at the number listed below.

Respectfully submitted,

WILMER CUTLER & PICKERING

Date: 6/17/02

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VERSION WITH MARKINGS TO SHOW CHANGES MADE

IN THE SPECIFICATION:

On page 1, paragraph beginning at line 6 has been amended as follows:

U.S. Patent Application Serial No. [_/___, __] <u>09/974,818</u>, entitled "INJECTION COLD EMITTER WITH NEGATIVE ELECTRON AFFINITY BASED ON WIDE-GAP SEMICONDUCTOR STRUCTURE WITH CONTROLLING BASE" (Attorney Docket No. 10007287-1).

IN THE CLAIMS:

- 1. (Once Amended) An electron emitter comprising:
- a p region;
- a dielectric layer formed above said p region; [and]
- a metallic layer formed above said dielectric layer; and

means for emitting electrons through said metallic layer.